



Docket No.: H0498.70217US02

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Lieber, et al.  
Serial No.: 10/588,833  
Confirmation No.: 4453  
Filed: August 9, 2006  
For: NANOSTRUCTURES CONTAINING METAL  
SEMICONDUCTOR COMPONENTS

Examiner: Not yet assigned  
Art Unit: 2667

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**CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)**

The undersigned hereby certifies that this document is being placed in the United States mail with first-class postage attached, addressed to MAIL STOP AMENDMENT, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the 30th day of July, 2007.

  
Angela M. Griffith

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**Mail Stop Amendment**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**STATEMENT FILED PURSUANT TO THE DUTY OF  
DISCLOSURE UNDER 37 C.F.R. §§1.56, 1.97 AND 1.98**

Sir:

Pursuant to the duty of disclosure under 37 C.F.R. §§1.56, 1.97 and 1.98, the Applicants request consideration of this Information Disclosure Statement.

**PART I: Compliance with 37 C.F.R. §1.97**

This Information Disclosure Statement has been filed before the mailing date of a first Office Action on the merits in the above-identified case.

No fee or certification is required.

PART II: Information Cited

The Applicants hereby make of record in the above-identified application the information listed on the attached form PTO-1449 (modified). The order of presentation of the references should not be construed as an indication of the importance of the references.

The Applicants hereby make the following additional information of record in the above-identified application.

The Applicants would like to bring to the Examiner's attention the following co-pending applications that may contain subject matter related to this application:

<u>Serial No.</u>	<u>Filing Date</u>	<u>Inventor(s)</u>	<u>Atty Docket No.</u>
10/196,337	07/16/02	Lieber, et al.	H0498.70187US00
10/734,086	12/11/03	Lieber, et al.	H0498.70203US01
10/812,653	03/29/04	Lieber, et al.	H0498.70112US01
11/012,549	12/15/04	Lieber, et al.	H0498.70164US01
11/137,784	05/25/04	Lieber, et al.	H0498.70243US00
11/172,408	02/14/05	Lieber, et al.	H0498.70187US04
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11/629,722	12/15/06	Wang, et al.	H0498.70222US01
11/807,186	05/25/07	Lu, et al.	H0498.70299US00

PART III: Remarks

Documents cited anywhere in the Information Disclosure Statement are enclosed unless otherwise indicated. It is respectfully requested that:

1. The Examiner consider completely the cited information, along with any other information, in reaching a determination concerning the patentability of the present claims;

2. The enclosed form PTO-1449 be signed by the Examiner to evidence that the cited information has been fully considered by the Patent and Trademark Office during the examination of this application;

3. The citations for the information be printed on any patent which issues from this application.

By submitting this Information Disclosure Statement, the Applicants make no representation that a search has been performed, of the extent of any search performed, or that more relevant information does not exist.

By submitting this Information Disclosure Statement, the Applicants make no representation that the information cited in the Statement is, or is considered to be, material to patentability as defined in 37 C.F.R. §1.56(b).

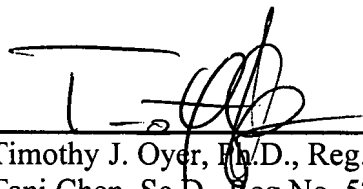
By submitting this Information Disclosure Statement, the Applicants make no representation that the information cited in the Statement is, or is considered to be, in fact, prior art as defined by 35 U.S.C. §102.

Notwithstanding any statements by the Applicants, the Examiner is urged to form his own conclusion regarding the relevance of the cited information.

An early and favorable action is hereby requested.

Respectfully submitted,

By:

  
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Docket No.: H0498.70217US02

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FORM PTO 51749/A (Modified)

# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

APPLICATION NO.: 10/588,833	ATTY. DOCKET NO.: H0498.70217US02
FILING DATE: August 9, 2006	CONFIRMATION NO.: 4453
APPLICANT: Lieber, et al.	
GROUP ART UNIT: 2667	EXAMINER: Not yet assigned

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				GROUP ART UNIT: 2667		EXAMINER: Not yet assigned	
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				GROUP ART UNIT: 2667		EXAMINER: Not yet assigned	
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FORM PTO-1449/A and B (Modified)  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>				APPLICATION NO.: 10/588,833		ATTY. DOCKET NO.: H0498.70217US02	
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				GROUP ART UNIT: 2667		EXAMINER: Not yet assigned	
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